

Advances in Raman Spectroscopy of Graphene and Layered Materials

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Raman spectroscopy is an integral part of graphene research [1]. It is used to determine the number and orientation of layers, the quality and types of edges, and the effects of perturbations, such as electric and magnetic fields, strain, doping, disorder and functional groups[2,3]. I will review the state of the art, future directions and open questions in Raman spectroscopy of graphene and related materials, focussing on the effect of disorder[3,4], doping[5,6] and deep UV laser excitation[7]. I will then consider the shear [8] and layer breathing modes(LBMs)[9], due to relative motions of the planes, either perpendicular or parallel to their normal. These modes are present in all layered materials[10,11]. Their detection allows one to directly probe the interlayer interactions [10,11]. They can also be used to determine the elastic constants associated with these displacements: the shear and out-of-plane elastic moduli[12]. This paves the way to the use of Raman spectroscopy to uncover the interface coupling of two-dimensional hybrids and heterostructures[10-12].

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